

LIST OF PUBLICATIONS OF DR. UTPAL GANGOPADHYAY

1. “Black silicon layer formation for application in solar cells”, J.S. Yoo, I.O. Parm, U. Gangopadhyay, Kyunghae Kim, S.K. Dhungel, D. Mangalaraj and Junsin Yi , Solar Energy Materials and Solar Cells, 90, (2006), Pages 3085-3093.
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 5. “Modeling and simulation of layer-transferred thin silicon solar cell with quasi monocrystalline porous silicon as active layer” M. Banerjee, S.K. Dutta, U. Gangopadhyay, D. Majumdar and H. Saha, Solid-State Electronics, 49(2005), Pages 1282-1291.
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